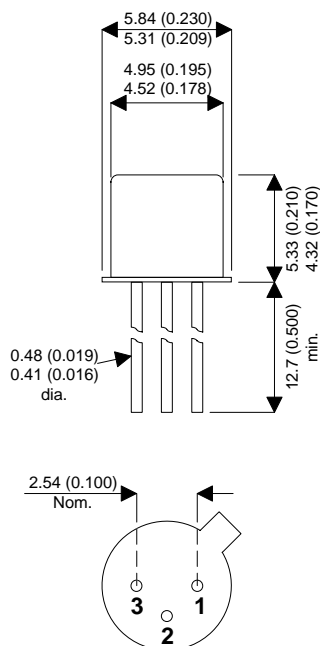


MECHANICAL DATA

Dimensions in mm (inches)


**MEDIUM POWER SILICON
NPN PLANAR TRANSISTOR**

**General Purpose Bipolar NPN
Transistor in a hermetically sealed
TO18 (TO-206AA) Metal Package.**

$$V_{CEO} = 65V$$

$$I_C = 500mA$$

$$P_{TOT} = 300mW$$

TO18 PACKAGE (TO-206AA)
Underside View

Pin 1 = Emitter Pin 2 = Base Pin 3 = Collector

ABSOLUTE MAXIMUM RATINGS ($T_{case} = 25^{\circ}C$ unless otherwise stated)

| | | |
|-----------------|---|------------------------|
| V_{CBO} | Collector – Base Voltage | 65V |
| V_{CEO} | Collector – Emitter Voltage | 65V |
| V_{EBO} | Emitter – Base Voltage | 5V |
| I_C | Collector Current | 500mA |
| P_{TOT} | Dissipation @ $T_{amb} = 25^{\circ}C$ | 300mW |
| | Derating linearly | 2mW/ $^{\circ}C$ |
| $R_{\theta JC}$ | Thermal Resistance | 500 $^{\circ}C/W$ |
| T_{stg}, T_j | Storage and Operatuing Junction Temperature | -65 to 175 $^{\circ}C$ |

Semelab Plc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

ELECTRICAL CHARACTERISTICS ($T_{\text{case}} = 25^{\circ}\text{C}$ unless otherwise stated)

| Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
|--|---|------|------|------|---------------|
| $V_{\text{CEO(SUS)}}$ Collector – Emitter Sustaining Voltage | $I_{\text{C}} = 10\text{mA}$ $I_{\text{B}} = 0$ | 65 | | | V |
| $V_{\text{CE(sat)}}$ Collector – Emitter Saturation Voltage | $I_{\text{C}} = 50\text{mA}$ $I_{\text{B}} = 5\text{mA}$ | | | 0.2 | |
| $V_{\text{BE(sat)}}$ Base – Emitter Saturation Voltage | $I_{\text{C}} = 75\text{mA}$ $I_{\text{B}} = 3\text{mA}$ | | | 1.2 | |
| I_{CBO} Collector Cut-off Current | $V_{\text{CB}} = 65\text{V}$ $I_{\text{E}} = 0$ | | | 0.5 | μA |
| I_{EBO} Emitter - Base Reverse Current | $V_{\text{EB}} = 5\text{V}$ $I_{\text{C}} = 0$ | | | 0.1 | μA |
| h_{FE} DC Current Gain | $V_{\text{CE}} = 0.4\text{V}$ $I_{\text{C}} = 1\text{mA}$ | 35 | | | |
| | $V_{\text{CE}} = 0.4\text{V}$ $I_{\text{C}} = 10\text{mA}$ | 50 | | 200 | |
| | $V_{\text{CE}} = 0.4\text{V}$ $I_{\text{C}} = 30\text{mA}$ | 35 | | | |
| | $V_{\text{CE}} = 0.75\text{V}$ $I_{\text{C}} = 75\text{mA}$ | 25 | | | |
| f_{T} Transition Frequency | $V_{\text{CE}} = 6\text{V}$ $I_{\text{C}} = 10\text{mA}$ | 50 | | | MHz |
| C_{ob} Output Capacitance | $V_{\text{CE}} = 6\text{V}$ $I_{\text{E}} = 0$ $f = 1\text{MHz}$ | | | 20 | pF |

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